

# **2SA1313** TRANSISTOR (PNP)

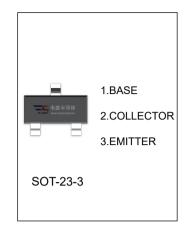
### **FEATURES**

Excellent h<sub>FE</sub> Linearity

:  $h_{FE(2)} = 25(Min)at V_{CE} = -6V, I_{C} = -400mA$ .

High Voltage :V<sub>CEO</sub>=-50V(Min)

• Complements to the 2SC3325.



## MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	-50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-50	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
Ic	Collector Current -Continuous	-500	mA
Pc	Collector Power Dissipation	200	mW
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55~+150	℃

### **ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-100μA,I <sub>E</sub> =0	-50			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =-1mA,I <sub>B</sub> =0	-50			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-100μA,I <sub>C</sub> =0	-5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =-50V,I <sub>E</sub> =0			-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =-5V,I <sub>C</sub> =0			-0.1	μA
	h <sub>FE(1)</sub>	V <sub>CE</sub> =-1V,I <sub>C</sub> =-100mA	70		240	
DC current gain	h <sub>FE(2)</sub>	$V_{CE}$ =-6 $V$ , $I_{C}$ =-400mA O	25			
		Y	40			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-100mA,I <sub>B</sub> =-10mA			-0.25	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> =-1V,I <sub>C</sub> =-100mA			-1	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =-6V,I <sub>C</sub> =-20mA		200		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-6V,I <sub>E</sub> =0,f=1MHz		13		pF

## CLASSIFICATION OF h<sub>FE(1)</sub>

Rank	0	Υ		
Range	70-140	120-240		



